NSN 5961-01-056-5017

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-056-5017 **Inclosure Material:** Metal **Overall Length:** 0.800 inches **Function For Which Designed:** Switching **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-4 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 reverse voltage, peak **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current absolute and 1.00 amperes forward current, average outside diameter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: